# NSN 5961-01-309-8673

Transistor - Page 1 of 1



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# Inclosure Material:

Metal

**Overall Length:** 

1.550 inches

# **Overall Height:**

0.300 inches

# Overall Width:

1.050 inches

# Mounting Facility Quantity:

2

## Internal Configuration:

## Field effect

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-204aa

#### **Mounting Method:**

Unthreaded hole

## Features Provided:

Hermetically sealed case

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 80.0 drain to gate voltage and 20.0 gate to source voltage

## **Current Rating Per Characteristic:**

20.00 amperes drain current and 60.00 amperes off-state current, peak

## Power Rating Per Characteristic:

100.0 watts total device dissipation

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

#### **Terminal Type And Quantity:**

2 pin and 1 case

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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